NSN 5961-01-321-3714

Unitized Semiconductor Devices - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5961-01-321-3714 **Inclosure Material:** Ceramic **Overall Length:** Between 0.750 inches and 0.785 inches **Terminal Length:** Between 0.100 inches and 0.165 inches **Overall Height:** 0.200 inches **Overall Width:** Between 0.245 inches and 0.271 inches **Component Name And Quantity:** 13 semiconductor device diode **Mounting Method: Terminal Features Provided:** Burn in and hermetically sealed case **Semiconductor Material:** Silicon all semiconductor device diode Voltage Rating In Volts Per Characteristic: 40.0 reverse voltage, peak all semiconductor **Current Rating Per Characteristic:** 350.00 milliamperes source cutoff current preset all semiconductor **Maximum Operating Tempurature Per Measurement Point:** 150.0 degrees celsius ambient air **Special Features:** All semiconductor device diode junction pattern arrangement: pn **Precious Material And Location:** Terminals option. Gold **Precious Material:** Gold **Terminal Type And Quantity:** 14 pin Shelf Life: N/a **Unit Of Measure: Demilitarization:** Yes - demil/mli

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